

Features

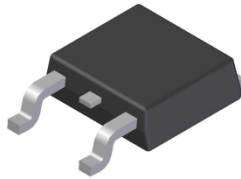
- $BV_{CEO} > 50V$
 - $I_C = 2A$ Continuous Collector Current
 - $I_{CM} = 3A$ Peak Pulse Current
 - Ideal for Power Switching or Amplification Applications
 - **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
 - **Halogen and Antimony Free. "Green" Device (Note 3)**
- The MJD2873Q is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

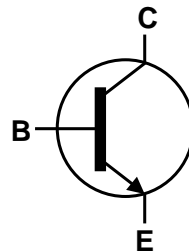
Mechanical Data

- Package: TO252 (DPAK)
- Package Material: Molded Plastic, "Green" Molding Compound
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.34 grams (Approximate)

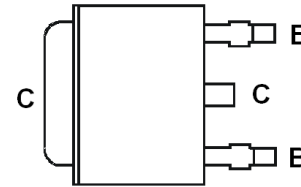
TO252 (DPAK)



Top View



Device Schematic



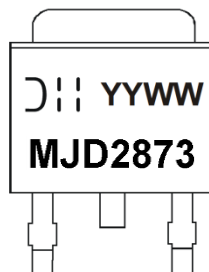
Pin Out Configuration
Top View

Ordering Information (Note 4)

Orderable Part Number	Package	Marking	Reel size (inches)	Tape width (mm)	Packing	
					Qty.	Carrier
MJD2873Q-13	TO252	MJD2873	13	16	2,500	Reel

- Notes:
1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



MJD2873 = Product Type Marking Code
 DII = Manufacturers' Code Marking
 YYWW = Date Code Marking
 YY = Last Digit of Year (ex: 23 = 2023)
 WW = Week Code (01 – 53)

Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	70	V
Collector-Emitter Voltage	V _{CEO}	50	V
Emitter-Base Voltage	V _{EBO}	7	V
Continuous Collector Current	I _C	2	A
Peak Pulse Collector Current	I _{CM}	3	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation	P _D	(Note 5)	2.60
		(Note 6)	2.30
		(Note 7)	1.45
Thermal Resistance, Junction to Ambient Air	R _{θJA}	(Note 5)	48
		(Note 6)	54
		(Note 7)	86
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device mounted with the exposed collector pad on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Same as note (5), except mounted on 25mm x 25mm 1oz copper.
 7. Same as note (5), except mounted on minimum recommended pad (MRP) layout.
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Thermal Characteristics

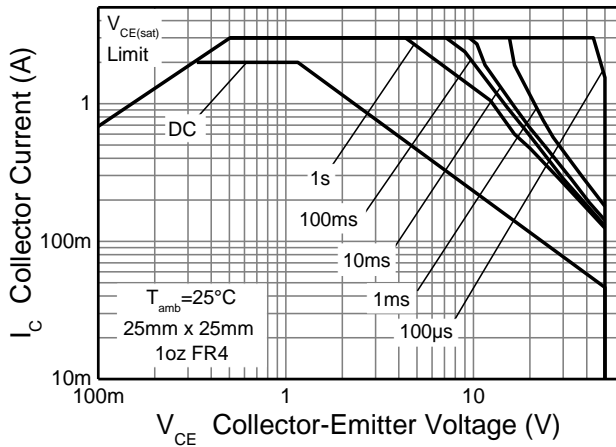


Figure 1. Safe Operating Area

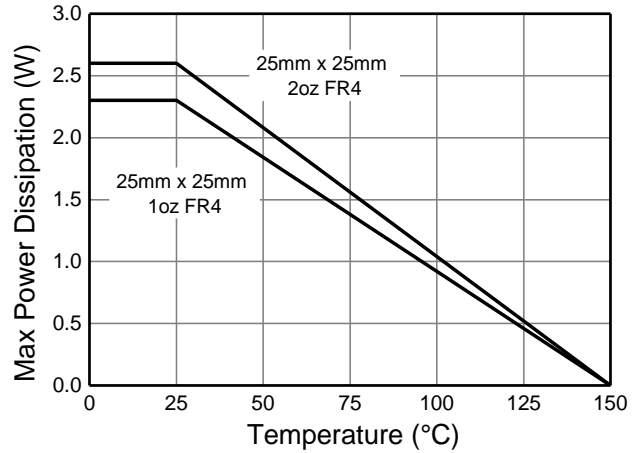


Figure 2. Derating Curve

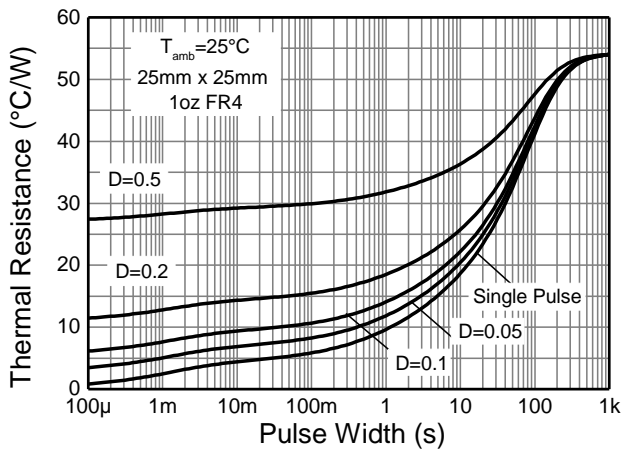


Figure 4. Transient Thermal Impedance

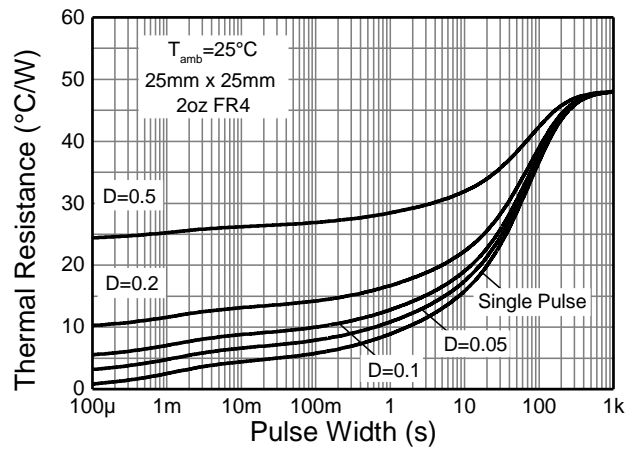


Figure 3. Transient Thermal Impedance

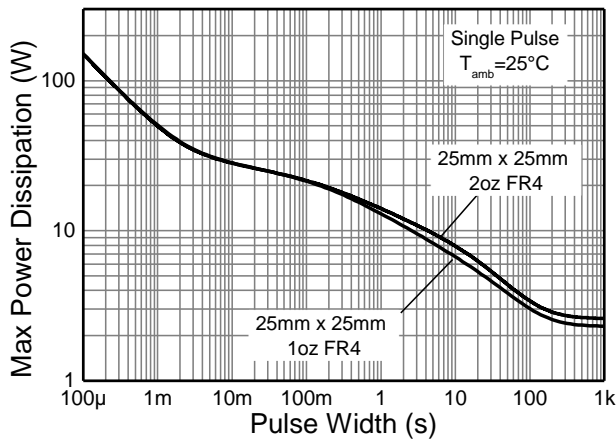


Figure 5. Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	70	—	—	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	50	—	—	V	I _C = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	—	—	V	I _E = 100μA
Collector Cut-off Current	I _{CES}	—	—	100	nA	V _{CE} = 50V
Collector-Base Cut-off Current	I _{CBO}	—	—	100	nA	V _{CB} = 70V
Emitter Cut-off Current	I _{EBO}	—	—	100	nA	V _{EB} = 6V
Collector-Emitter Saturation Voltage (Note 9)	V _{CE(sat)}	—	—	0.3	V	I _C = 1A, I _B = 50mA
Base-Emitter Saturation Voltage (Note 9)	V _{BE(sat)}	—	—	1.2	V	I _C = 1A, I _B = 50mA
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(on)}	—	—	1.2 0.95	V	I _C = 1A, V _{CE} = 2V I _C = 0.75A, V _{CE} = 1.6V
DC Current Gain (Note 9)	h _{FE}	120 40 80	—	—	—	V _{CE} = 2V, I _C = 0.5A V _{CE} = 2V, I _C = 2A V _{CE} = 1.6V, I _C = 0.75A
Current Gain-Bandwidth Product	f _T	65	—	—	MHz	I _C = 0.1A, V _{CE} = 10V, f = 100MHz
Output Capacitance	C _{obo}	—	26	—	pF	V _{CB} = 10V, f = 1MHz
Input Capacitance	C _{ibo}	—	45	—	pF	V _{EB} = 0.5V, f = 1MHz
Delay Time	t _d	—	29	—	ns	I _C = 0.5A, V _{CC} = 10V I _{B1} = -I _{B2} = 50mA
Rise Time	t _r	—	20	—	ns	
Storage Time	t _s	—	378	—	ns	
Fall Time	t _f	—	57	—	ns	

Note: 9. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

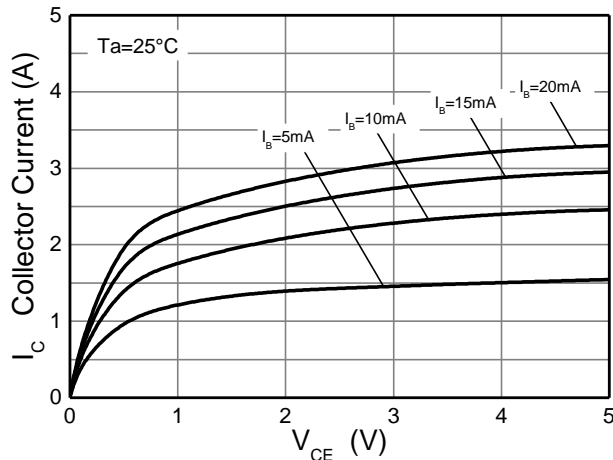


Figure 6. I_C v V_{CE}

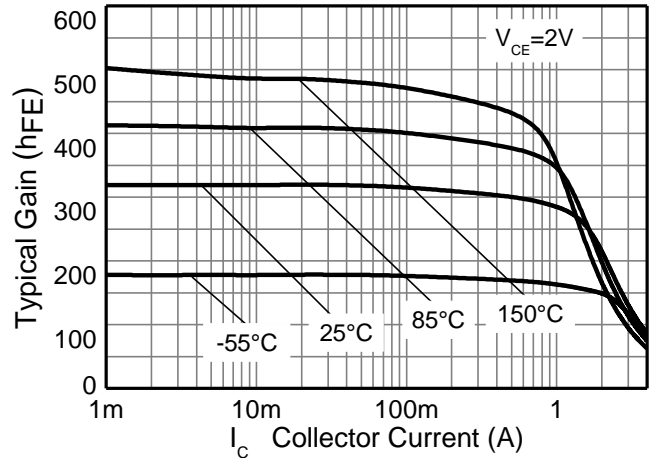


Figure 7. h_{FE} v I_C

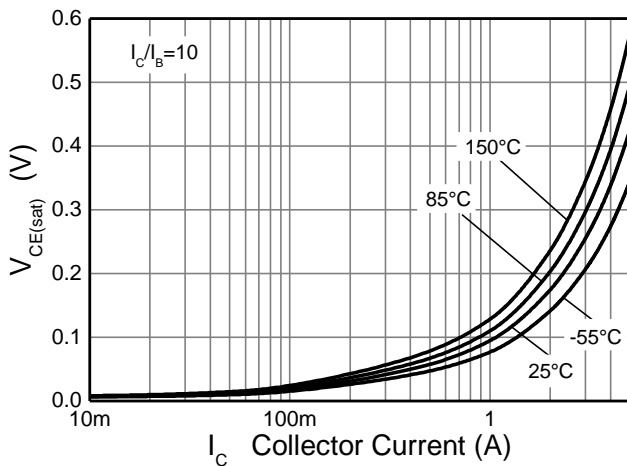


Figure 8. $V_{CE(sat)}$ v I_C

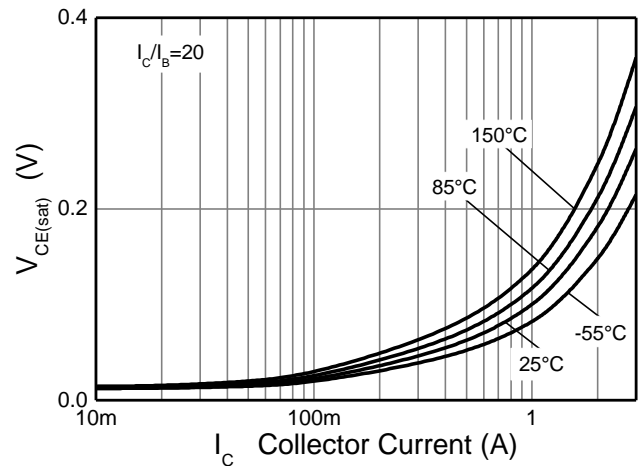


Figure 9. $V_{CE(sat)}$ v I_C

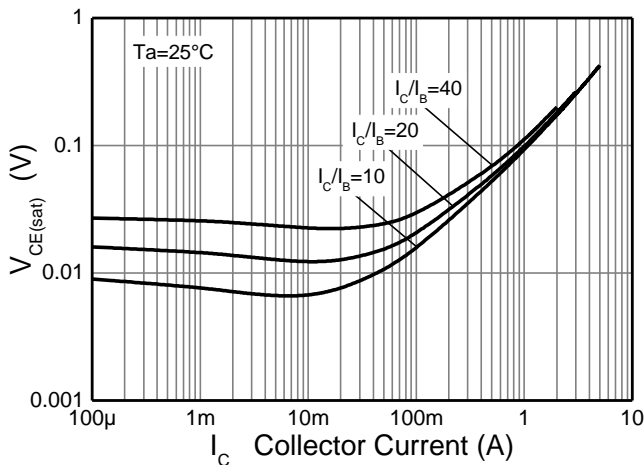


Figure 10. $V_{CE(sat)}$ v I_C

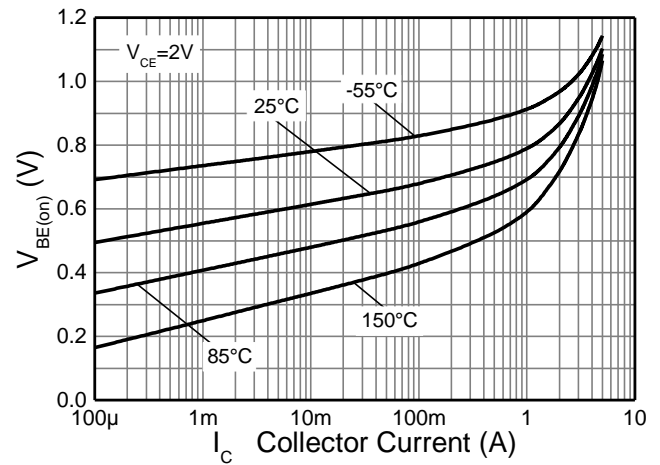


Figure 11. $V_{BE(on)}$ v I_C

Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

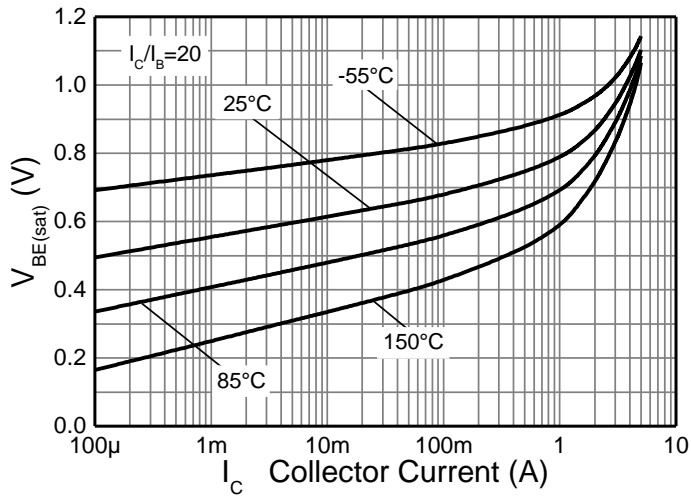
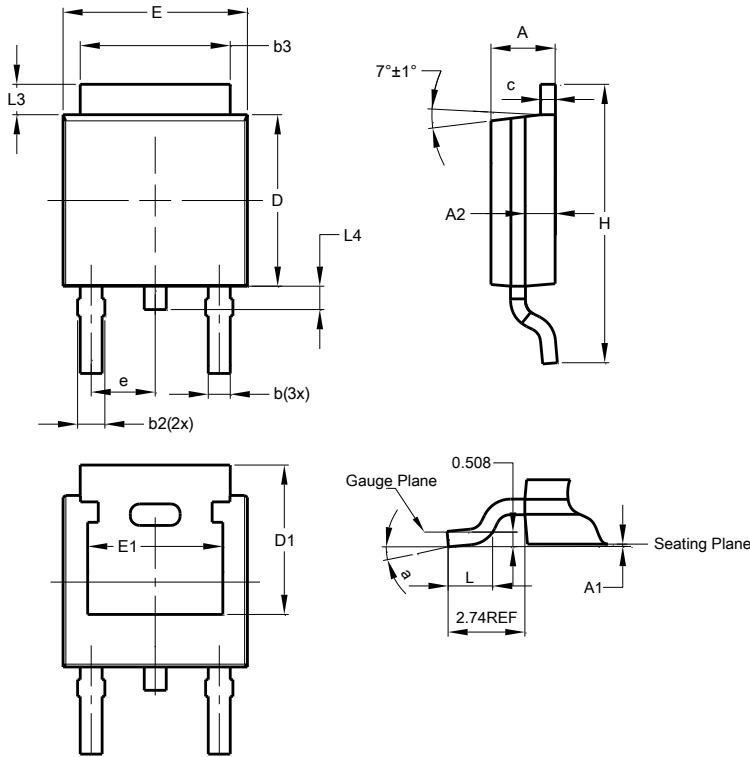


Figure 12. $V_{BE(sat)}$ v I_C

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

TO252 (DPAK)

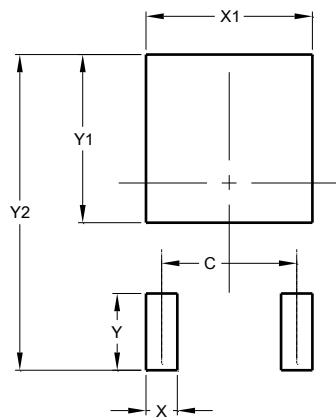


TO252 (DPAK)			
Dim	Min	Max	Typ
A	2.19	2.39	2.29
A1	0.00	0.13	0.08
A2	0.97	1.17	1.07
b	0.64	0.88	0.783
b2	0.76	1.14	0.95
b3	5.21	5.50	5.33
c	0.45	0.58	0.531
D	6.00	6.20	6.10
D1	5.21	--	--
e	2.286 BSC		
E	6.45	6.70	6.58
E1	4.32	--	--
H	9.40	10.41	9.91
L	1.40	1.78	1.59
L3	0.88	1.27	1.08
L4	0.64	1.02	0.83
a	0°	10°	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)
C	4.572
X	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

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